

# DATA SHEET

**74HC04; 74HCT04**

**Hex inverter**

Product specification

2003 Jul 23

Supersedes data of 1993 Sep 01

**Hex inverter****74HC04; 74HCT04****FEATURES**

- Complies with JEDEC standard no. 8-1A
- ESD protection:  
HBM EIA/JESD22-A114-A exceeds 2000 V  
MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 to +85 °C and -40 to +125 °C.

**QUICK REFERENCE DATA**GND = 0 V; T<sub>amb</sub> = 25 °C; t<sub>r</sub> = t<sub>f</sub> ≤ 6.0 ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC04	HCT04	
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay nA to nY	C <sub>L</sub> = 15 pF; V <sub>CC</sub> = 5 V	7	8	ns
C <sub>I</sub>	input capacitance		3.5	3.5	pF
C <sub>PD</sub>	power dissipation capacitance per gate	notes 1 and 2	21	24	pF

**Notes**

1. C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz;f<sub>o</sub> = output frequency in MHz;C<sub>L</sub> = output load capacitance in pF;V<sub>CC</sub> = supply voltage in Volts;

N = total load switching outputs;

 $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

2. For 74HC04: the condition is V<sub>I</sub> = GND to V<sub>CC</sub>.

For 74HCT04: the condition is V<sub>I</sub> = GND to V<sub>CC</sub> - 1.5 V.**FUNCTION TABLE**

See note 1.

INPUT	OUTPUT
nA	nY
L	H
H	L

**Note**

1. H = HIGH voltage level;

L = LOW voltage level.

## Hex inverter

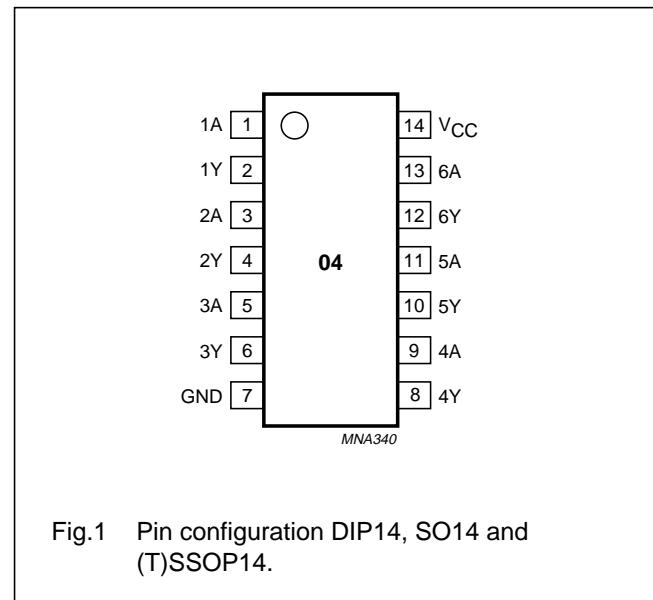
74HC04; 74HCT04

## ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE
74HC04N	-40 to +125 °C	14	DIP14	plastic	SOT27-1
74HCT04N	-40 to +125 °C	14	DIP14	plastic	SOT27-1
74HC04D	-40 to +125 °C	14	SO14	plastic	SOT108-1
74HCT04D	-40 to +125 °C	14	SO14	plastic	SOT108-1
74HC04DB	-40 to +125 °C	14	SSOP14	plastic	SOT337-1
74HCT04DB	-40 to +125 °C	14	SSOP14	plastic	SOT337-1
74HC04PW	-40 to +125 °C	14	TSSOP14	plastic	SOT402-1
74HCT04PW	-40 to +125 °C	14	TSSOP14	plastic	SOT402-1
74HC04BQ	-40 to +125 °C	14	DHVQFN14	plastic	SOT762-1
74HCT04BQ	-40 to +125 °C	14	DHVQFN14	plastic	SOT762-1

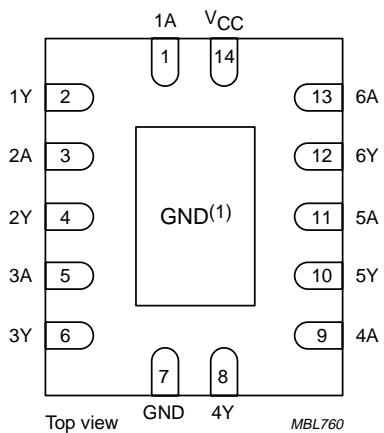
## PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1Y	data output
3	2A	data input
4	2Y	data output
5	3A	data input
6	3Y	data output
7	GND	ground (0 V)
8	4Y	data output
9	4A	data input
10	5Y	data output
11	5A	data input
12	6Y	data output
13	6A	data input
14	V <sub>CC</sub>	supply voltage



## Hex inverter

74HC04; 74HCT04



- (1) The die substrate is attached to this pad using conductive die attach material. It can not be used as a supply pin or input.

Fig.2 Pin configuration DHVQFN14.

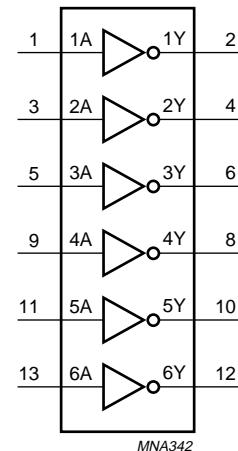


Fig.3 Logic symbol.

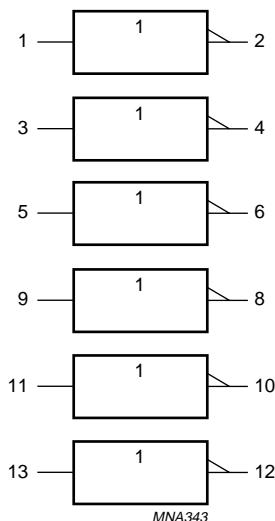


Fig.4 IEC logic symbol.

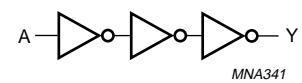


Fig.5 Logic diagram (one inverter).

## Hex inverter

## 74HC04; 74HCT04

## RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	74HC04			74HCT04			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		0	–	V <sub>CC</sub>	0	–	V <sub>CC</sub>	V
V <sub>O</sub>	output voltage		0	–	V <sub>CC</sub>	0	–	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature	see DC and AC characteristics per device	–40	+25	+125	–40	+25	+125	°C
t <sub>r</sub> , t <sub>f</sub>	input rise and fall times	V <sub>CC</sub> = 2.0 V	–	–	1000	–	–	–	ns
		V <sub>CC</sub> = 4.5 V	–	6.0	500	–	6.0	500	ns
		V <sub>CC</sub> = 6.0 V	–	–	400	–	–	–	ns

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage		–0.5	+7.0	V
I <sub>IK</sub>	input diode current	V <sub>I</sub> < –0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	–	±20	mA
I <sub>OK</sub>	output diode current	V <sub>O</sub> < –0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	–	±20	mA
I <sub>O</sub>	output source or sink current	–0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V	–	±25	mA
I <sub>CC</sub> , I <sub>GND</sub>	V <sub>CC</sub> or GND current		–	±50	mA
T <sub>stg</sub>	storage temperature		–65	+150	°C
P <sub>tot</sub>	power dissipation DIP14 package other packages	T <sub>amb</sub> = –40 to +125 °C; note 1	–	750	mW
		T <sub>amb</sub> = –40 to +125 °C; note 2	–	500	mW

## Notes

- For DIP14 packages: above 70 °C derate linearly with 12 mW/K.
- For SO14 packages: above 70 °C derate linearly with 8 mW/K.  
For SSOP14 and TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.  
For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

## Hex inverter

74HC04; 74HCT04

## DC CHARACTERISTICS

## Type 74HC04

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = 25 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		2.0	1.5	1.2	–	V
			4.5	3.15	2.4	–	V
			6.0	4.2	3.2	–	V
V <sub>IL</sub>	LOW-level input voltage		2.0	–	0.8	0.5	V
			4.5	–	2.1	1.35	V
			6.0	–	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = –20 µA I <sub>O</sub> = –20 µA I <sub>O</sub> = –4.0 mA I <sub>O</sub> = –20 µA I <sub>O</sub> = –5.2 mA	2.0	1.9	2.0	–	V
			4.5	4.4	4.5	–	V
			4.5	3.98	4.32	–	V
			6.0	5.9	6.0	–	V
			6.0	5.48	5.81	–	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 20 µA I <sub>O</sub> = 20 µA I <sub>O</sub> = 4.0 mA I <sub>O</sub> = 20 µA I <sub>O</sub> = 5.2 mA	2.0	–	0	0.1	V
			4.5	–	0	0.1	V
			4.5	–	0.15	0.26	V
			6.0	–	0	0.1	V
			6.0	–	0.16	0.26	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	6.0	–	0.1	±0.1	µA
I <sub>OZ</sub>	3-state output OFF current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND	6.0	–	–	±0.5	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	6.0	–	–	2	µA

## Hex inverter

74HC04; 74HCT04

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 to +85 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		2.0	1.5	—	—	V
			4.5	3.15	—	—	V
			6.0	4.2	—	—	V
V <sub>IL</sub>	LOW-level input voltage		2.0	—	—	0.5	V
			4.5	—	—	1.35	V
			6.0	—	—	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = -20 µA I <sub>O</sub> = -20 µA I <sub>O</sub> = -4.0 mA I <sub>O</sub> = -20 µA I <sub>O</sub> = -5.2 mA	2.0	1.9	—	—	V
			4.5	4.4	—	—	V
			4.5	3.84	—	—	V
			6.0	5.9	—	—	V
			6.0	5.34	—	—	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 20 µA I <sub>O</sub> = 20 µA I <sub>O</sub> = 4.0 mA I <sub>O</sub> = 20 µA I <sub>O</sub> = 5.2 mA	2.0	—	—	0.1	V
			4.5	—	—	0.1	V
			4.5	—	—	0.33	V
			6.0	—	—	0.1	V
			6.0	—	—	0.33	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	6.0	—	—	±1.0	µA
I <sub>OZ</sub>	3-state output OFF current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND	6.0	—	—	±5.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	6.0	—	—	20	µA

## Hex inverter

74HC04; 74HCT04

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 to +125 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		2.0	1.5	—	—	V
			4.5	3.15	—	—	V
			6.0	4.2	—	—	V
V <sub>IL</sub>	LOW-level input voltage		2.0	—	—	0.5	V
			4.5	—	—	1.35	V
			6.0	—	—	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = -20 µA I <sub>O</sub> = -20 µA I <sub>O</sub> = -20 µA I <sub>O</sub> = -4.0 mA I <sub>O</sub> = -5.2 mA	2.0	1.9	—	—	V
			4.5	4.4	—	—	V
			6.0	5.9	—	—	V
			4.5	3.7	—	—	V
			6.0	5.2	—	—	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 20 µA I <sub>O</sub> = 20 µA I <sub>O</sub> = 20 µA I <sub>O</sub> = 4.0 mA I <sub>O</sub> = 5.2 mA	2.0	—	—	0.1	V
			4.5	—	—	0.1	V
			6.0	—	—	0.1	V
			4.5	—	—	0.4	V
			6.0	—	—	0.4	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	6.0	—	—	±1.0	µA
I <sub>OZ</sub>	3-state output OFF current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND	6.0	—	—	±10.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	6.0	—	—	40	µA

## Hex inverter

74HC04; 74HCT04

**Type 74HCT04**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>cc</sub> (V)				
<b>T<sub>amb</sub> = 25 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	1.6	–	V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	–	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = –20 µA I <sub>O</sub> = –4.0 mA	4.5 4.5	4.4 3.84	4.5 4.32	– –	V V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 20 µA I <sub>O</sub> = 4.0 mA	4.5 4.5	– –	0 0.15	0.1 0.26	V V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5	–	–	±0.1	µA
I <sub>OZ</sub>	3-state output OFF current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	–	–	±0.5	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	–	–	2	µA
ΔI <sub>CC</sub>	additional supply current per input	V <sub>I</sub> = V <sub>CC</sub> – 2.1 V; I <sub>O</sub> = 0	4.5 to 5.5	–	120	432	µA
<b>T<sub>amb</sub> = –40 to +85 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	–	–	V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	–	–	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = –20 µA I <sub>O</sub> = –4.0 mA	4.5 4.5	4.4 3.84	– –	– –	V V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 20 µA I <sub>O</sub> = 4.0 mA	4.5 4.5	– –	– –	0.1 0.33	V V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5	–	–	±1.0	µA
I <sub>OZ</sub>	3-state output OFF current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	–	–	±5.0	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	–	–	20	µA
ΔI <sub>CC</sub>	additional supply current per input	V <sub>I</sub> = V <sub>CC</sub> – 2.1 V; I <sub>O</sub> = 0	4.5 to 5.5	–	–	540	µA

## Hex inverter

## 74HC04; 74HCT04

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V <sub>CC</sub> (V)				
<b>T<sub>amb</sub> = -40 to +125 °C</b>							
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	—	—	V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	—	—	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = -20 µA I <sub>O</sub> = -4.0 mA	4.5 4.5	4.4 3.7	— —	— —	V V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> I <sub>O</sub> = 20 µA I <sub>O</sub> = 4.0 mA	4.5 4.5	— —	— —	0.1 0.4	V V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5	—	—	±1.0	µA
I <sub>OZ</sub>	3-state output OFF current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	±10	µA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0	5.5	—	—	40	µA
ΔI <sub>CC</sub>	additional supply current per input	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; I <sub>O</sub> = 0	4.5 to 5.5	—	—	590	µA

## Hex inverter

74HC04; 74HCT04

## AC CHARACTERISTICS

## Family 74HC04

GND = 0 V;  $t_r = t_f \leq 6.0$  ns;  $C_L = 50$  pF.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	$V_{CC}$ (V)				
<b><math>T_{amb} = 25^\circ C</math></b>							
$t_{PHL}/t_{PLH}$	propagation delay nA to nY	see Figs 6 and 7	2.0	—	25	85	ns
			4.5	—	9	17	ns
			6.0	—	7	14	ns
$t_{THL}/t_{TLH}$	output transition time	see Figs 6 and 7	2.0	—	19	75	ns
			4.5	—	7	15	ns
			6.0	—	6	13	ns
<b><math>T_{amb} = -40</math> to <math>+85^\circ C</math></b>							
$t_{PHL}/t_{PLH}$	propagation delay nA to nY	see Figs 6 and 7	2.0	—	—	105	ns
			4.5	—	—	21	ns
			6.0	—	—	18	ns
$t_{THL}/t_{TLH}$	output transition time	see Figs 6 and 7	2.0	—	—	95	ns
			4.5	—	—	19	ns
			6.0	—	—	16	ns
<b><math>T_{amb} = -40</math> to <math>+125^\circ C</math></b>							
$t_{PHL}/t_{PLH}$	propagation delay nA to nY	see Figs 6 and 7	2.0	—	—	130	ns
			4.5	—	—	26	ns
			6.0	—	—	22	ns
$t_{THL}/t_{TLH}$	output transition time	see Figs 6 and 7	2.0	—	—	110	ns
			4.5	—	—	22	ns
			6.0	—	—	19	ns

## Hex inverter

74HC04; 74HCT04

**Family 74HCT04** $GND = 0 \text{ V}$ ;  $t_r = t_f \leq 6.0 \text{ ns}$ ;  $C_L = 50 \text{ pF}$ .

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	$V_{CC} (\text{V})$				
<b><math>T_{amb} = 25^\circ\text{C}</math></b>							
$t_{PHL}/t_{PLH}$	propagation delay nA to nY	see Figs 6 and 7	4.5	—	10	19	ns
$t_{THL}/t_{TLH}$	output transition time	see Figs 6 and 7	4.5	—	7	15	ns
<b><math>T_{amb} = -40 \text{ to } +85^\circ\text{C}</math></b>							
$t_{PHL}/t_{PLH}$	propagation delay nA to nY	see Figs 6 and 7	4.5	—	—	24	ns
$t_{THL}/t_{TLH}$	output transition time	see Figs 6 and 7	4.5	—	—	19	ns
<b><math>T_{amb} = -40 \text{ to } +125^\circ\text{C}</math></b>							
$t_{PHL}/t_{PLH}$	propagation delay nA to nY	see Figs 6 and 7	4.5	—	—	29	ns
$t_{THL}/t_{TLH}$	output transition time	see Figs 6 and 7	4.5	—	—	22	ns

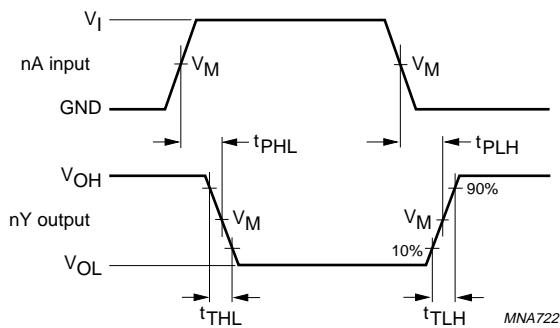
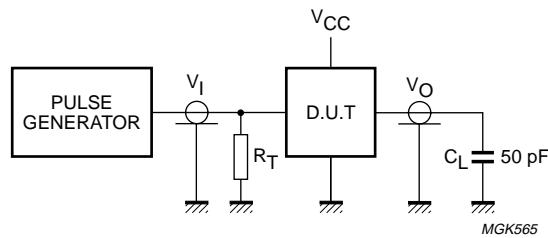
**AC WAVEFORMS**For 74HC04:  $V_M = 50\%$ ;  $V_I = \text{GND to } V_{CC}$ .For 74HCT04:  $V_M = 1.3 \text{ V}$ ;  $V_I = \text{GND to } 3.0 \text{ V}$ .

Fig.6 Waveforms showing the data input (nA) to data output (nY) propagation delays and the output transition times.

## Hex inverter

74HC04; 74HCT04



Definitions for test circuit:

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

Fig.7 Load circuitry for switching times.

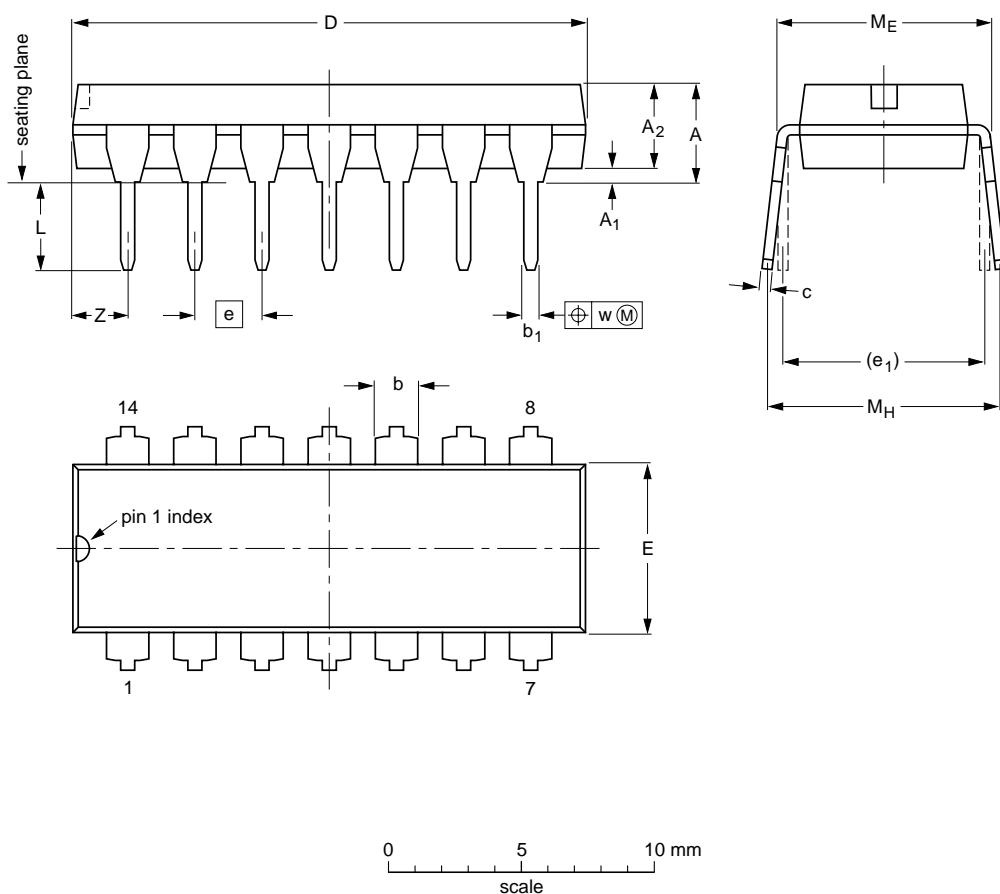
## Hex inverter

74HC04; 74HCT04

## PACKAGE OUTLINES

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



## DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.02	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

## Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

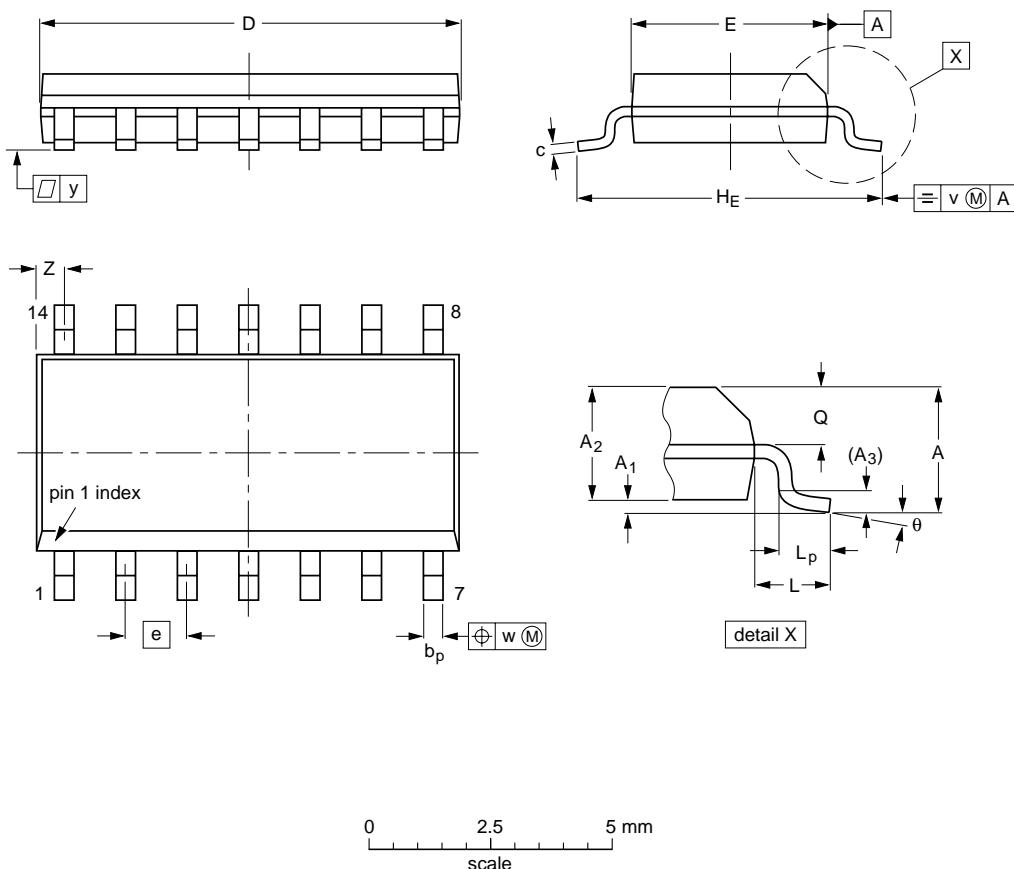
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT27-1	050G04	MO-001	SC-501-14			99-12-27 03-02-13

## Hex inverter

74HC04; 74HCT04

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	Q	v	w	y	z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

## Note

- Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

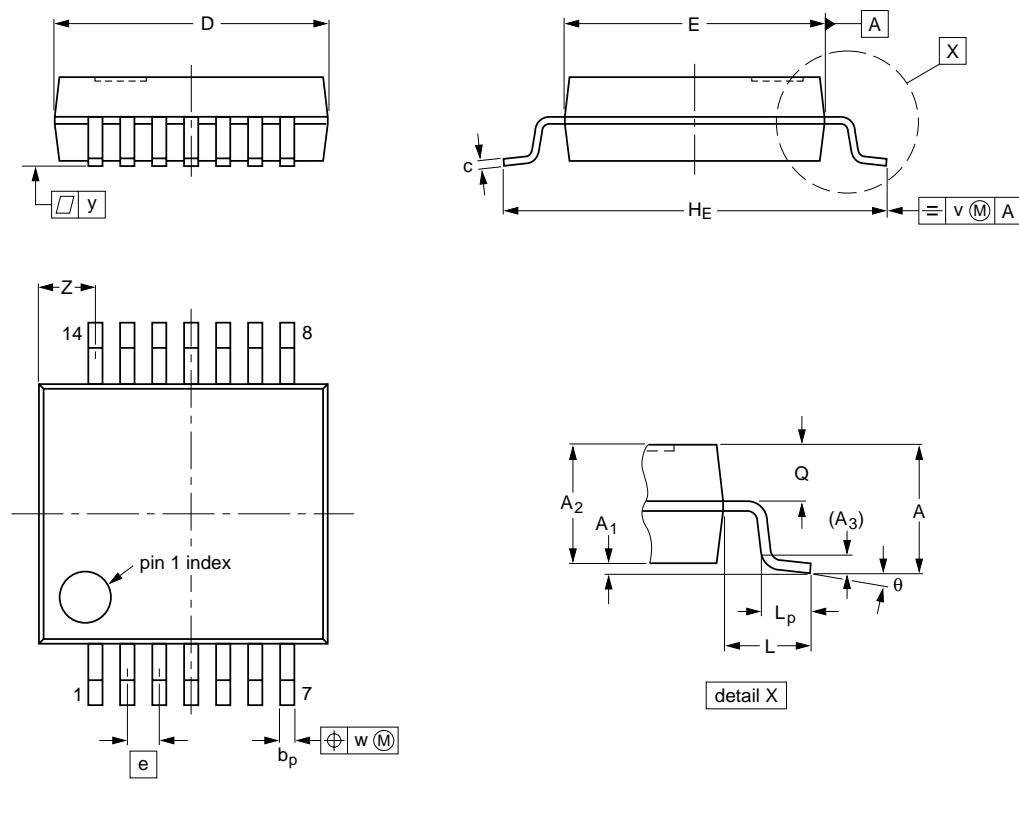
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT108-1	076E06	MS-012				99-12-27 03-02-19

## Hex inverter

74HC04; 74HCT04

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



## DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	Q	v	w	y	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

## Note

- Plastic or metal protrusions of 0.25 mm maximum per side are not included.

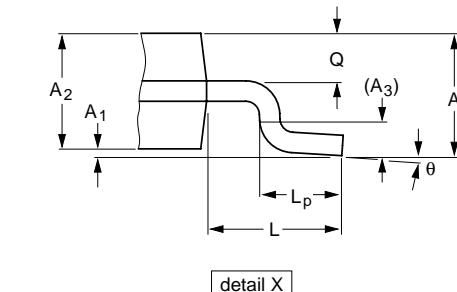
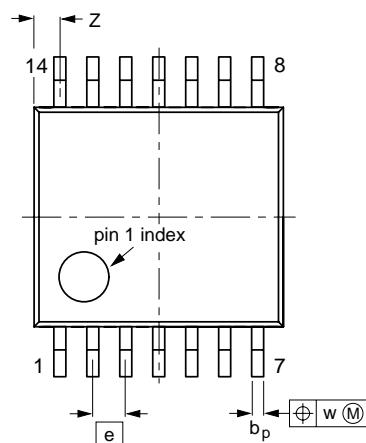
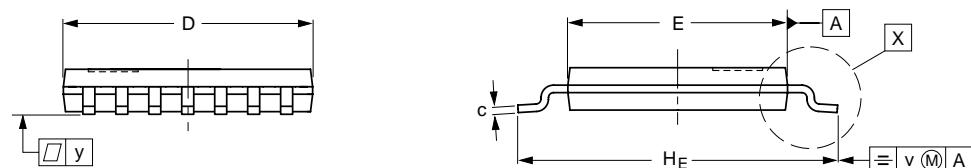
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT337-1		MO-150				-99-12-27 03-02-19

## Hex inverter

74HC04; 74HCT04

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



0      2.5      5 mm  
scale

## DIMENSIONS (mm are the original dimensions)

UNIT	A max.	$A_1$	$A_2$	$A_3$	$b_p$	c	$D^{(1)}$	$E^{(2)}$	e	$H_E$	L	$L_p$	Q	v	w	y	$Z^{(1)}$	$\theta$
mm	1.1 0.05	0.15 0.80	0.95	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

## Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

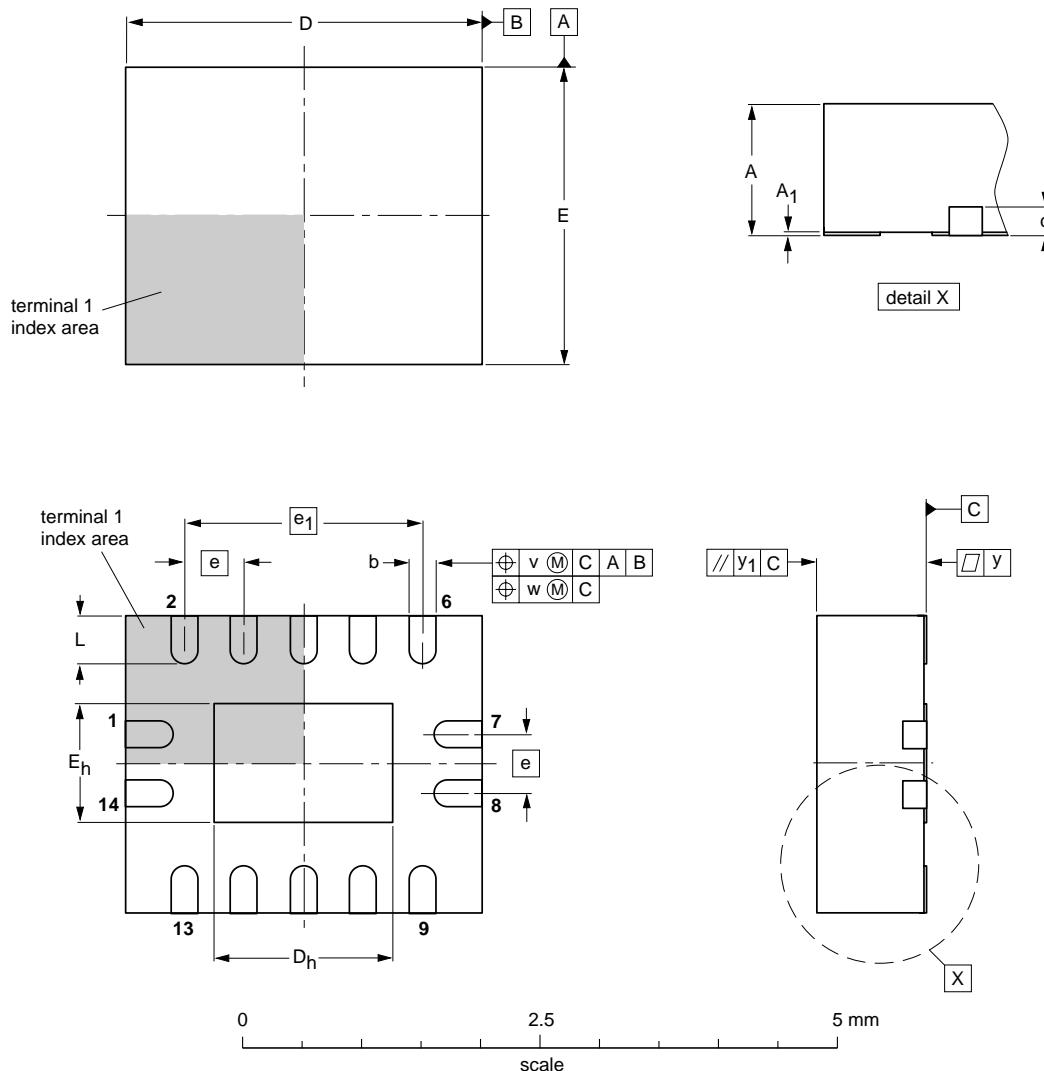
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT402-1		MO-153				-99-12-27 03-02-18

## Hex inverter

74HC04; 74HCT04

**DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm**

SOT762-1



**DIMENSIONS** (mm are the original dimensions)

DIMENSIONS (mm are the original dimensions)																
UNIT	A <sup>(1)</sup> max.	A <sub>1</sub>	b	c	D <sup>(1)</sup>	D <sub>h</sub>	E <sup>(1)</sup>	E <sub>h</sub>	e	e <sub>1</sub>	L	v	w	y	y <sub>1</sub>	
mm	1	0.05 0.00	0.30 0.18	0.2	3.1 2.9	1.65 1.35	2.6 2.4	1.15 0.85	0.5	2	0.5 0.3	0.1	0.05	0.05	0.1	

### Note

1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT762-1	---	MO-241	---			02-10-17 03-01-27

## Hex inverter

## 74HC04; 74HCT04

**DATA SHEET STATUS**

<b>LEVEL</b>	<b>DATA SHEET STATUS<sup>(1)</sup></b>	<b>PRODUCT STATUS<sup>(2)(3)</sup></b>	<b>DEFINITION</b>
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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